

Application

- \cdot Motor drive
- · Inverter, Converter
- · Photovoltaics, wind power generation.
- · Induction heating equipment.

Features

- 1) Low surge, low switching loss.
- 2) High-speed switching possible.
- 3) Reduced temperature dependence.

Construction

This product is a half bridge module consisting of SiC-DMOS and SiC-SBD from ROHM.

•Dimensions & Pin layout (Unit : mm)



Circuit diagram



•Absolute maximum ratings (Tj = 25°C)

Parameter	Symbol	Conditions	Limit	Unit V	
Drain-source voltage	V _{DSS}	G-S short	1200		
Gate-source voltage(+)		D-S short	22	V	
Gate-source voltage(-)	V _{GSS}	D-3 short	-6	V	
G - S voltage (t _{surge} <300ns)	V _{GSSsurge}	D-S short	-10 to 26	V	
Drain current *1	I _D	DC(Tc=60°C)	134	Α	
	I _{DRM}	I _{DRM} Pulse (Tc=60°C) 1ms * ²		Α	
Source current *1	I _S	DC(Tc =60°C) V _{GS} =18V	134	Α	
Source current	I _{SRM} Pulse (Tc=60°C) 1ms V _{GS} =18V ^{*2}		240	А	
Total power disspation *3	Ptot	Tc=25°C	935	W	
Max Junction Temperature	Tjmax		175	°C	
Junction temperature	Tj		-40 to150	°C	
Storage temperature	Tstg		-40 to125	°C	
Isolation voltage	Visol	Terminals to baseplate, f=60Hz AC 1min.2500		Vrms	
Mounting torque		Main Terminals : M6 screw	4.5	N·m	
Mounting torque	_	Mounting to heat shink : M5 screw	3.5	N·m	

(*1) Case temperature (Tc) is defined on the surface of base plate just under the chips.

(*2) Repetition rate should be kept within the range where temperature rise if die should not exceed T_{jmax}.

(*3) T_i is less than 175°C

Example of acceptable V_{GS} waveform



•Electrical characteristics (Tj=25°C)

Parameter	Symbol	Conditions		Min.	Тур.	Max.	Unit
On-state static Drain-Source Voltage	V _{DS(on)}	I _D =120A, V _{GS} =18V	T _j =25°C	_	2.1	3.2	V
			T _j =125°C	_	3.1	4.6	
			T _j =150°C	Ι	3.4	5.2	
Drain Cutoff Current	I _{DSS}	V _{DS} =1200V, V _{GS} =0V		-	_	2	mA
Souce-Drain Voltage	V _{SD}	V _{GS} =0V, I _S =120A	T _j =25°C	-	1.7	2.1	V
			T _j =125°C	_	2.2	2.7	
			T _j =150°C	-	2.4	3.2	
			T _j =25°C	1	1.3	_	
		V _{GS} =18V, I _S =120A	T _j =125°C	-	1.7	_	
			T _j =150°C	_	1.8	_	
Gate-Source Threshold Voltage	V _{GS(th)}	V _{DS} =10V, I _D =22mA		1.6	2.3	4	V
Gate-Source Leak Current	I _{GSS}	V_{GS} =22V, V_{DS} =0V		1	_	0.5	
		V_{GS} = -6V, V_{DS} =0V		-0.5	_	_	μA
Switching Characteristics	t _{d(on)}	V _{GS(on)} =18V, V _{GS(off)} =0V			45	_	ns
	t _r	V_{DS} =600V I _D =120A R _G =3.9Ω inductive load		-	50	—	
	t _{rr}			Ι	30	_	
	t _{d(off)}			1	170	_	
	t _f			Ι	60	_	
Input Capacitance	Ciss	V _{DS} =10V, V _{GS} =0V, f=1MHz		Ι	14	_	nF
Gate Registance	R _{Gint}	T _j =25°C			1.8	_	Ω
Stray Inductance	Ls				25	—	nH
Creepage Distance	_	Terminal to heat sink			11.5	_	mm
		Terminal to terminal			19.0	_	mm
Clearance Distance	_	Terminal to heat sink			9.5	_	mm
		Terminal to terminal			13.0	_	mm
Junction-to-Case Thermal	R _{th} (j-c)	DMOSFET (1/2 module) * ⁴		Ι	_	0.16	°C/W
Resistance	νth(J Ο)	SBD (1/2 module) * ⁴	BD (1/2 module) * ⁴		_	0.21	
Case-to-heat sink	R _{th} (c-f)	Case to heat sink, per 1	_	0.035	_		
Thermal resistance	¹ \th(∪ ⁻ 1)	Thermal grease applied * ⁵					

(*4) Measurement of Tc is to be done at the point just under the chip.

- (*5) Typical value is measured by using thermally conductive grease of λ=0.9W/(m • K).
- (*6) SiC devices have lower short cuicuit withstand capability due to high current density. Please be advised to pay careful attention to short cuicuit accident and try to adjust protection time to shutdown them as short as possible.
- (*7) If the Product is used beyond absolute maximum ratings defined in the Specifications, as its internal structure may be dameged, please replace such Product with a new one.

<Wavelength for Switching Test>





Fig.1 Typical Output Characteristics

Fig.2 Drain-Source Voltage vs. Drain Current



Fig.3 Drain-Source Voltage vs. Gate-Source Voltage 10 T_i=25°C 9 Drain-Source Voltage : V_{DS} [V] 8 7 6 5 4 I_D=180A 3 I_D=120A 2 I_D=80A 1 I_D=40A 0 10 15 20 25

Gate-Source Voltage : V_{GS} [V]





Junction Temperature : T_j [°C]

Drain-Source Voltage : V_{DS} [V]



Fig.5 Forward characteristic of Diode

Fig.6 Forward characteristic of Diode



Source-Drain Voltage : V_{SD} [V]

Fig.7 Drain Current vs. Gate-Source Voltage

Fig.8 Drain Current vs. Gate-Source Voltage



15



Fig.9 Switching Characteristics [T_i=25°C]



Fig.10 Switching Characteristics [T_i=125°C]









Fig.16 Switching Characteristics vs. Gate Resistance [T_i=125°C]



Gate Resistance : R_G [Ω]









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